

**4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY**
**Product Summary**

<b>V<sub>BR</sub>(MIN)</b>	<b>I<sub>PP</sub>(MAX)</b>	<b>C<sub>I/O</sub> (TYP)</b>
6V	5.5A	0.55pF

**Description**

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for use in Automotive applications.

**Applications**

- Typically Used for High Speed Ports such as USB 2.0, USB 3.0, DVI™, HDMI™, Ethernet Port, IEEE, MDDI, PCI Express®, SATA/eSATA

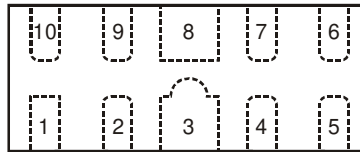
**Features**

- Clamping Voltage: 9V at 10A 100ns, TLP  
9.4V at 5.5A 8µs/20µs
- IEC 61000-4-2 (ESD): Air — ±16kV, Contact — ±14kV
- IEC 61000-4-5 (Lightning): ±5.5A (8/20µs)
- Four Channels of ESD Protection
- Low Channel Input Capacitance of 0.55pF Typical
- TLP Dynamic Resistance: 0.25Ω
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. “Green” Device (Note 3)**
- The DT1240-04LPQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**  
<https://www.diodes.com/quality/product-definitions/>

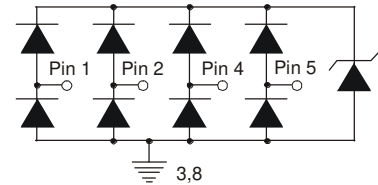
**Mechanical Data**

- Case: U-DFN2510-10
- Case Material: Molded Plastic, “Green” Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.038 grams (Approximate)

Pin #	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	V <sub>SS</sub>



Pin Description (Top View)



Device Schematic

**Ordering Information** (Note 4)

Part Number	Compliance	Marking Code	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DT1240-04LPQ-7	Automotive	BC7	7	8	3,000/Tape & Reel

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  - See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, “Green” and Lead-free.
  - Halogen- and Antimony-free “Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  - For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**


BC7 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: I = 2021)  
 M = Month (ex: 9 = September)

## Date Code Key

Year	2017	...	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	E	...	I	J	K	L	M	N	O	P	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current, per IEC 61000-4-5	I <sub>PP</sub>	5.5	A	I/O to V <sub>SS</sub> , 8/20μs
Peak Pulse Power, per IEC 61000-4-5	P <sub>PP</sub>	60	W	I/O to V <sub>SS</sub> , 8/20μs
Operating Voltage (DC)	V <sub>DC</sub>	6	V	I/O to V <sub>SS</sub>
ESD Protection – Contact Discharge, per IEC 61000-4-2	V <sub>ESD_CONTACT</sub>	±14	kV	I/O to V <sub>SS</sub>
ESD Protection – Air Discharge, per IEC 61000-4-2	V <sub>ESD_AIR</sub>	±16	kV	I/O to V <sub>SS</sub>
Operating Temperature	T <sub>OP</sub>	-55 to +85	°C	—
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C	—

**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	P <sub>D</sub>	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	R <sub>θJA</sub>	360	°C/W

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Reverse Working Voltage	V <sub>RWM</sub>	—	—	5.5	V	—
Reverse Current	I <sub>R</sub>	—	—	0.5	μA	V <sub>R</sub> = 5V, I/O to V <sub>SS</sub>
Reverse Breakdown Voltage	V <sub>BR</sub>	6	—	—	V	I <sub>R</sub> = 1mA, I/O to V <sub>SS</sub>
Forward Clamping Voltage	V <sub>F</sub>	-1.0	-0.85	—	V	I <sub>F</sub> = -15mA, I/O to V <sub>SS</sub>
Holding Voltage	V <sub>H</sub>	5.5	—	—	V	—
Reverse Clamping Voltage (Note 6)	V <sub>C</sub>	—	9.4	11	V	I <sub>PP</sub> = 5.5A, I/O to V <sub>SS</sub> , 8/20μs
Trigger Voltage	V <sub>TRIG</sub>	—	—	9.5	V	—
ESD Clamping Voltage	V <sub>ESD</sub>	—	9	—	V	TLP, 10A, t <sub>P</sub> = 100ns, I/O to V <sub>SS</sub>
Dynamic Reverse Resistance	R <sub>DIF-R</sub>	—	0.25	—	Ω	TLP, 10A, t <sub>P</sub> = 100ns, I/O to V <sub>SS</sub>
Dynamic Forward Resistance	R <sub>DIF-F</sub>	—	0.25	—	Ω	TLP, 10A, t <sub>P</sub> = 100ns, V <sub>SS</sub> to I/O
Channel Input Capacitance (Note 7)	C <sub>I/O</sub>	—	0.55	0.65	pF	V <sub>I/O</sub> = 2.5V, V <sub>SS</sub> = 0V, f = 1MHz
Delta C <sub>I/O</sub>	C <sub>I/OMAX</sub> -C <sub>I/OMIN</sub>	—	0.04	—	pF	C <sub>I/OMAX</sub> -C <sub>I/OMIN</sub>

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at <http://www.diodes.com/package-outlines.html>.

6. Clamping voltage value is based on an 8x20μs peak pulse current (I<sub>pp</sub>) waveform.

7 C<sub>I/O1</sub>=C<sub>PIN1</sub>+C<sub>PIN10</sub>, C<sub>I/O2</sub>=C<sub>PIN2</sub>+C<sub>PIN9</sub>, C<sub>I/O3</sub>=C<sub>PIN4</sub>+C<sub>PIN7</sub>, C<sub>I/O4</sub>=C<sub>PIN5</sub>+C<sub>PIN6</sub>.

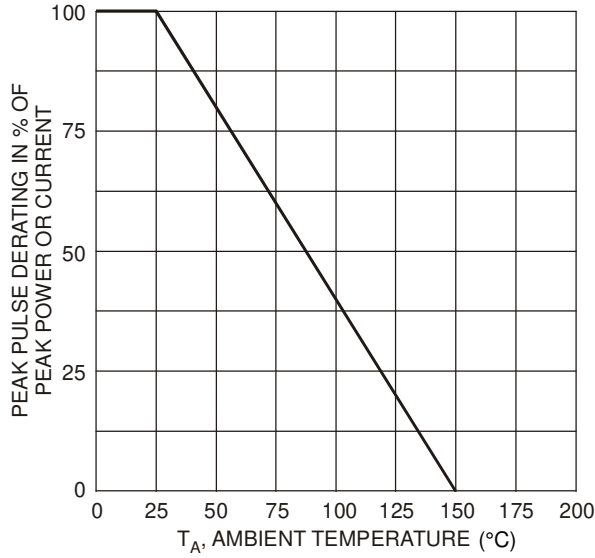


Figure 1 Pulse Derating Curve

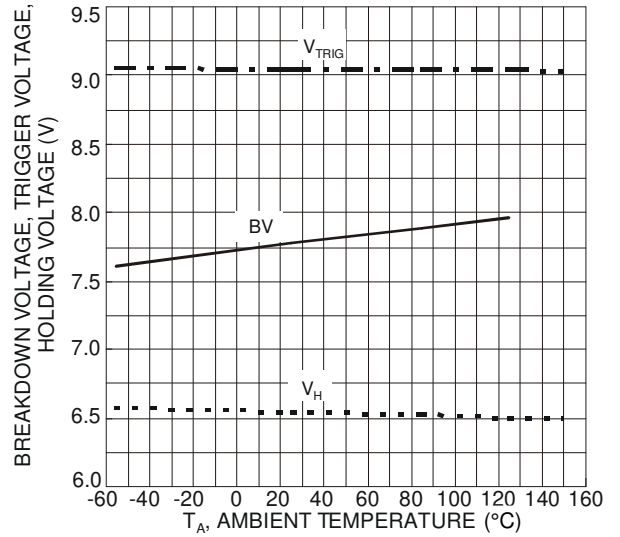


Figure 2 BV, Trigger Voltage, Holding Voltage vs. Ambient Temperature

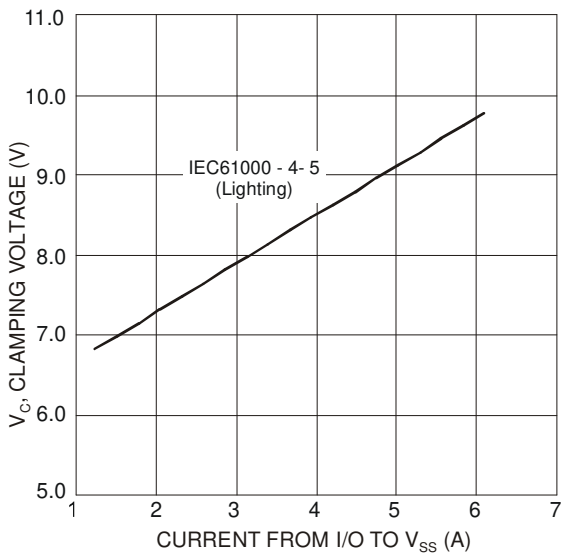


Figure 3 Clamping Voltage Characteristic

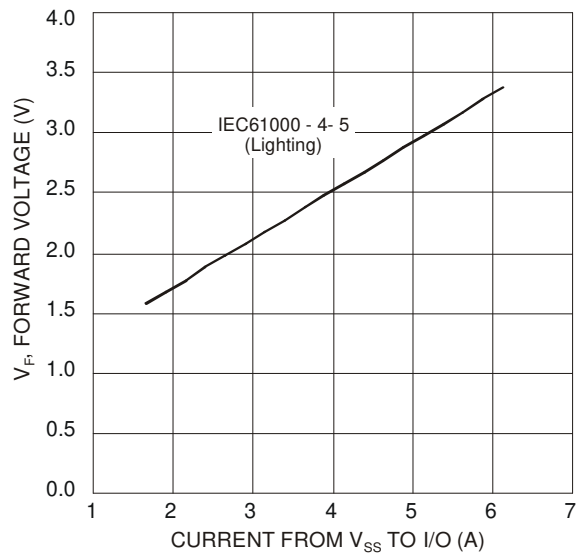


Figure 4 Forward Voltage Characteristic

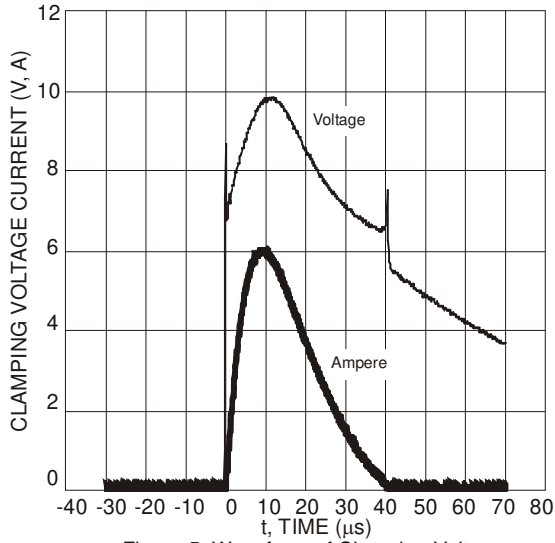


Figure 5 Waveform of Clamping Voltage, Current vs. Time (8/20μs, I/O to Vss)

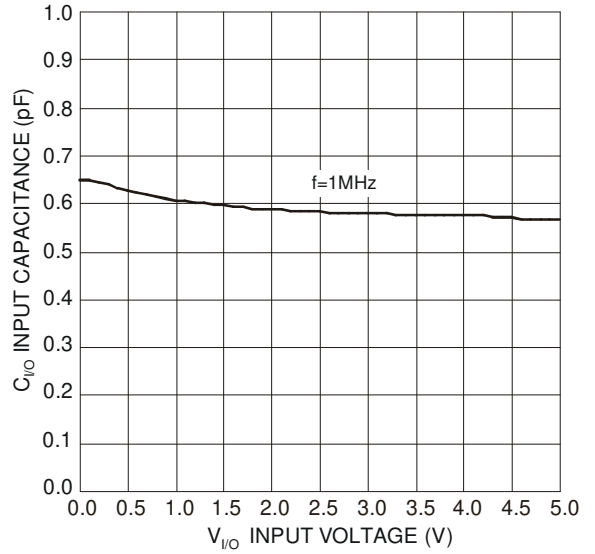


Figure 6 Input Capacitance vs. Input Voltage

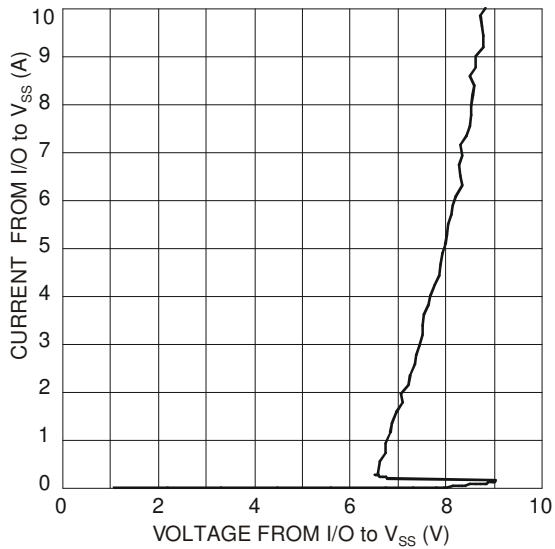
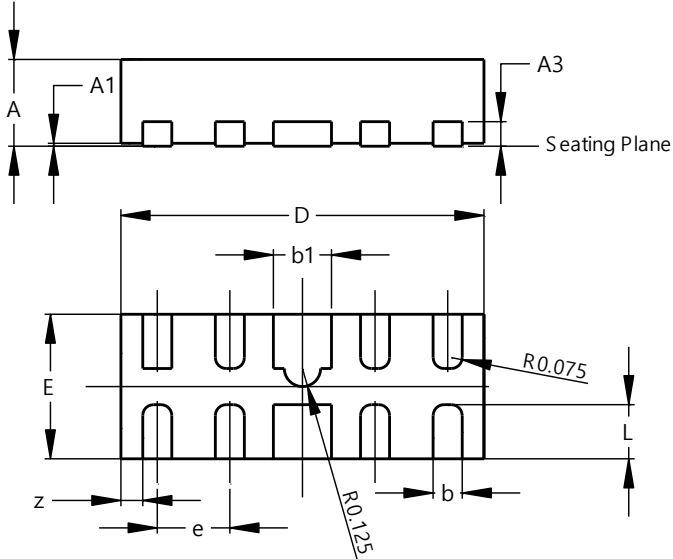


Figure 7 Current vs. Voltage

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**U-DFN2510-10**

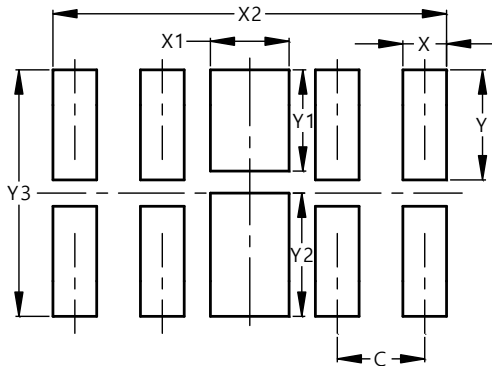


U-DFN2510-10			
Dim	Min	Max	Typ
A	0.545	0.605	0.575
A1	0.00	0.05	0.03
A3	-	-	0.13
b	0.15	0.25	0.20
b1	0.35	0.45	0.40
D	2.450	2.575	2.500
e	-	-	0.50
E	0.950	1.075	1.000
L	0.325	0.425	0.375
z	-	-	0.150
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**U-DFN2510-10**



Dimensions	Value (in mm)
C	0.500
X	0.250
X1	0.450
X2	2.250
Y	0.625
Y1	0.575
Y2	0.700
Y3	1.400

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